MC100EPT26

1:2 Fanout Differential LVPECL to LVTTL Translator

The MC100EPT26 is a 1:2 Fanout Differential LVPECL to LVTTL translator. Because LVPECL (Positive ECL) levels are used only +3.3V and ground are required. The small outline 8-lead SOIC package and the 1:2 fanout design of the EPT26 makes it ideal for applications which require the low skew duplication of a signal in a tightly packed PC board.

The VBB output allows the EPT26 to be used in a <u>single</u>-ended input mode. In this mode the VBB output is tied to the $\overline{D0}$ input for a non-inverting buffer or the D0 input for an inverting buffer. If used, the VBB pin should be bypassed to ground via a $0.01\mu F$ capacitator.

- 1.4ns Typical Propagation Delay
- 275MHz Fmax (Clock bit stream, not pseudo-random)
- Differential LVPECL inputs
- Small Outline SOIC Package
- 24mA TTL outputs
- Flowthrough Pinouts
- ESD Protection: >2KV HBM, >100V MM
- Internal Input Resistors: Pulldown on D, Pulldown and Pullup on \overline{D}
- Q Outputs will default LOW with inputs open or at VEE
- VBB Output
- New Differential Input Common Mode Range
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.
 For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 117 devices

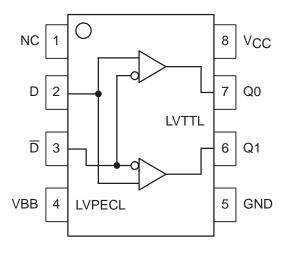


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram



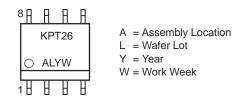
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MARKING DIAGRAM



*For additional information, see Application Note AND8002/D

PIN DESCRIPTION						
PIN	FUNCTION					
Q0, Q1	LVTTL Outputs					
D, $\overline{\overline{D}}$	Differential LVPECL Input Pair					
VCC	Positive Supply					
V _{BB}	Reference Voltage					
GND	Ground					

ORDERING INFORMATION

Device	Package	Shipping			
MC100EPT26D	SOIC	98 Units/Rail			
MC100EPT26DR2	SOIC	2500 Tape & Reel			

MC100EPT26

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit	
V _{CC}	Power Supply (GND = 0V)		0 to 3.8	VDC
VI	Input Voltage (GND = 0V, V _I not more positive th	an V _{CC})	0 to 3.8	VDC
l _{out}	Output Current	50 100	mA	
I _{BB}	V _{BB} Sink/Source Current†		± 0.5	mA
TA	Operating Temperature Range		-40 to +85	°C
T _{stg}	Storage Temperature		-65 to +150	°C
θЈΑ	Thermal Resistance (Junction-to-Ambient)	Still Air 500lfpm	190 130	°C/W
θJC	Thermal Resistance (Junction-to-Case)		41 to 44 ± 5%	°C/W
T _{sol}	Solder Temperature (<2 to 3 Seconds: 245°C des	265	°C	

^{*} Maximum Ratings are those values beyond which damage to the device may occur.

DC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$; GND = 0V; $T_A = -40^{\circ}C$ to $85^{\circ}C$)

Symbol	Characteristic	Min	Тур	Max	Unit
ICCH	Power Supply Current (Outputs set to HIGH)	10	20	18	mA
ICCL	Power Supply Current (Outputs set to LOW)	15	28	35	mA
V _{IH}	Input HIGH Voltage (V _{CC} = 3.3) (Note 1.)	2135		2420	mV
V _{IL}	Input LOW Voltage (V _{CC} = 3.3) (Note 1.)	1490		1825	mV
lн	Input HIGH Current			150	μΑ
IIL	Input LOW Current D	-150		0.5	μА
Vон	Output HIGH Voltage (I _{OH} = -3.0mA) (Note 2.)	2.4			V
VOL	Output LOW Voltage (I _{OL} = 24mA) (Note 2.)			0.5	V
los	Output Short Circuit Current	- 50		-150	mA
VIHCMR	Input HIGH Voltage Common Mode Range (Note 3.)	2.0		3.3	V
V _{BB}	Output Voltage Reference		2.0		V

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

AC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$; GND = 0V)

			-40°C		25°C			85°C				
Symbol	Characteristic		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Toggle Frequency (Note 4.)		275			275			275			MHz
tPLH, tPHL	Propagation Delay to Output Differential		500	1500	2500	500	1500	2500	500	1500	2500	ps
tSK+ + tSK tSKPP	Output-to-Output Skew++ Output-to-Output Skew Part-to-Part Skew (Note 5.)			60 25 500			60 25 500			60 25 500		ps
[†] JITTER	Cycle-to-Cycle Jitter			TBD			TBD			TBD		ps
VPP	Input Voltage Swing (Diff.)		150	800	1200	150	800	1200	150	800	1200	mV
t _r	Output Rise/Fall Times (20% – 80%)	Q, Q	330	500	900	330	500	900	330	550	950	ps

F_{max} guaranteed for functionality only. V_{OL} and V_{OH} levels are guaranteed at DC only.
 Skews are measured between outputs under identical transitions.

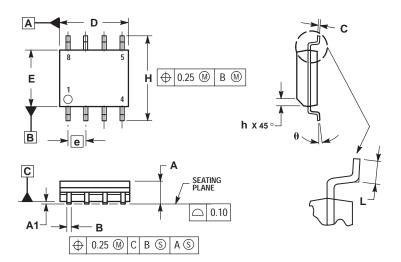
[†] Use for inputs of same package only.

All values vary 1:1 with V_{CC}.
 All loading with 500 ohms to GND, CL = 20pF.
 V_{IHCMR} min varies 1:1 with GND, max varies 1:1 with V_{CC}.

MC100EPT26

PACKAGE DIMENSIONS

SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-06 ISSUE T



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. DIMENSIONS ARE IN MILLIMETER.
 3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS							
DIM	MIN	MAX						
Α	1.35	1.75						
A1	0.10	0.25						
В	0.35	0.49						
С	0.19	0.25						
D	4.80	5.00						
Ε	3.80	4.00						
е	1.27	BSC						
Н	5.80	6.20						
h	0.25	0.50						
L	0.40	1.25						
θ	0 °	7 °						

MC100FPT26

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